

Abstract Submitted  
for the MAR15 Meeting of  
The American Physical Society

**Enhancement of Magnetic Anisotropy in Ultrathin Epitaxial  $\text{La}_{0.67}\text{Sr}_{0.33}\text{MnO}_3$  Thin Films via Nanostructure Engineering** ANIL RAJAPITAMAHUNI, LE ZHANG, JOHN BURTON, VIJAY SINGH, EVGENY TSYMBAL, XIA HONG, University of Nebraska-Lincoln — We report a more than ten-fold enhancement of magnetic anisotropy in nanostructured  $\text{La}_{0.67}\text{Sr}_{0.33}\text{MnO}_3$  (LSMO) thin films grown epitaxially on (001)  $\text{SrTiO}_3$  substrates. We have etched periodic linear trenches in 6 nm LSMO films, and investigated magnetic anisotropy in these nanostructured thin films via the planar Hall effect (PHE). These trenches have depth of 2 nm and periodicities of 200 - 400 nm. The PHE resistance of the un-patterned LSMO films exhibits sinusoidal angular dependence in an in-plane magnetic field, and shows four-fold sharp resistance switching below a critical magnetic field of 400 Oe, corresponding to a biaxial magnetic anisotropy of  $\sim 1 \times 10^5$  erg/cm<sup>3</sup> along  $\langle 110 \rangle$  directions. In the nanostructured samples, we observe an additional two-fold resistance switching feature, which persists in magnetic fields higher than 4000 Oe, corresponding to a uniaxial magnetic anisotropy  $> 1 \times 10^6$  erg/cm<sup>3</sup> along one of the biaxial magnetic easy axes. This significant enhancement of magnetic anisotropy cannot be accounted for by shape anisotropy or a uniform strain modulation. We also discuss the effects of the orientation and periodicity of the nano-trenches on the anisotropy enhancement.

Anil Rajapitamahuni  
University of Nebraska-Lincoln

Date submitted: 14 Nov 2014

Electronic form version 1.4